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Alfred A. Barney et al.

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: TEMPERATURE-SENSING COMPOSITION

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ngton, D.C. 20231

AMENDMENT

In response to the Office Action mailed April 29, 2002 ("Office Action"), Applicants
the following remarks. Please amend the application of fell submit the following remarks. Please amend the application as follows:

In the claims:

Amend claims 11, 12 and 15 as follows:

--11. (Amended) The method of claim 1, wherein the semiconductor nanocrystal is a member of a population that emits light in a spectral range of no great than about 75 nm full width at half max (FWHM).--

--12. (Amended) The method of claim 1, wherein the semiconductor nanocrystal is a member of a population exhibits less than a 15% rms deviation in diameter of the nanocrystals.--

15. (Amended) A temperature sensor comprising a matrix containing a semiconductor nanocrystal, the matrix formed from a semiconductor nanocrystal and a binder, a light source arranged to illuminate the semiconductor nanocrystal, and a detector arranged to detect light emitted from the semiconductor nanocrystal .--

Add new claims 49-50 as follows:

(New) The method of claim 1, wherein detecting emission of light from the sensor includes detecting emission intensity of light from the sensor.--

--50. (New) The method of claim 48, wherein detecting emission of light from the sensor includes detecting emission intensity of light from the sensor.--

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